

# **HD74LS221**

### **Dual Monostable Multivibrators**

REJ03D0458-0300 Rev.3.00 Jul.15.2005

This multivibrator features a negative-transition-triggered input and a positive-transition-triggered input either of which can be used as an inhibit input. Pulse triggering occurs at a particular voltage level and is not directly related to the transition time of the input pulse. Schmitt-trigger input circuitry (TTL hysteresis) for B input allows jitter-free triggering from inputs with transition rates as slow as 1 V/s, providing the circuit with excellent noise immunity of typically 1.2 V. A high immunity to  $V_{CC}$  noise of typically 1.5 V is also provided by internal latching circuitry. Once fired, the outputs are independent of further transitions of the A and B inputs and are a function of the timing components, or the output pulses can be terminated by the overriding clear. Input pulses may be of any duration relative to the output pulse. Output rise and fall times are TTL compatible and independent of pulse length.

Typical triggering and clearing sequence are illustrated as a part of the switching characteristics waveforms. Pulse width stability is achieved through internal compensation and is virtually independent of  $V_{CC}$  and temperature.

In most applications, pulse stability will only be limited by the accuracy of external timing components. Jitter-free operation is maintained over the full temperature and  $V_{CC}$  range for more than six decades of timing capacitance (10 pF to  $10 \, \mu F$ ) and more than one decade of timing resistance (2 k $\Omega$  to  $100 \, k\Omega$ ).

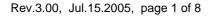
Throughout these ranges, pulse width is defined by the relationship:  $t_{w \text{ (out)}} = \text{Cext} \bullet \text{Rext} \bullet \text{1n 2}$ .

#### **Features**

• Ordering Information

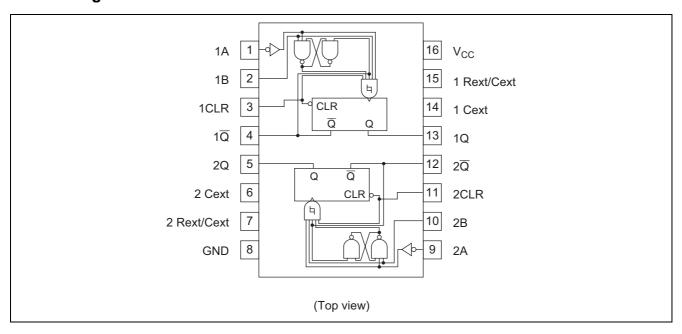
Part Name	Package Type	Package Code (Previous Code)	Package Abbreviation	Taping Abbreviation (Quantity)
HD74LS221P	DILP-16 pin	PRDP0016AE-B (DP-16FV)	Р	_
HD74LS221RPEL	SOP-16 pin (JEDEC)	PRSP0016DG-A (FP-16DNV)	RP	EL (2,500 pcs/reel)

Note: Please consult the sales office for the above package availability.





### **Pin Arrangement**



### **Function Table**

	Inputs	Outputs			
Clear	Α	В	Q	Q	
L	X	X	L	Н	
Х	Н	X	L	Н	
Х	X	L	L	Н	
Н	L	1	Л	ъ	
Н	<b>\</b>	Н	Л	ъ	
<b>↑</b>	L	Н	Л	ъ	

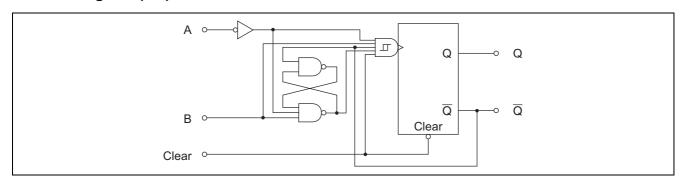
Notes: H; high level, L; low level, X; irrelevant.

↓; Transition from high to low level.

↑; Transition from low to high level.

 $\ \square$ ; one high-level pulse.  $\ \square$ ; one low-level pulse.

### **Block Diagram (1/2)**



## **Absolute Maximum Ratings**

Item	Symbol	Ratings	Unit
Supply voltage	V <sub>CC</sub>	7	V
Input voltage	V <sub>IN</sub>	7	V
Power dissipation	P <sub>T</sub>	400	mW
Storage temperature	Tstg	-65 to +150	°C

Note: Voltage value, unless otherwise noted, are with respect to network ground terminal.

## **Recommended Operating Conditions**

Item		Symbol	Min	Тур	Max	Unit	
Supply voltage		$V_{CC}$	4.75	5.00	5.25	V	
Output current		I <sub>OH</sub>	_	_	-400	μΑ	
Output current		$I_{OL}$	_	_	8	mA	
Operating temperature	e	$T_{opr}$	-20	25	75	°C	
Rate of rise or fall of Schmitt input, B		dV/dt	1	_	_	V/s	
input pulse	Logic Input, A	u v/ut	1	_	_	V/μs	
Input pulse width	A or B	t <sub>w (in)</sub>	40	_	_		
input puise width	Clear	t <sub>w (clear)</sub>	40	_	_	ns	
Setup time		t <sub>su</sub>	15	_	_	ns	
External timing resistance		R <sub>ext</sub>	1.4	_	100	kΩ	
External timing capacitance		C <sub>ext</sub>	0	_	1000	μF	
Duty ovolo	$R_T = 2 k\Omega$		_	_	50		
Duty cycle	R <sub>T</sub> = 100 kΩ		_	_	90		

### **Electrical Characteristics**

 $(Ta = -20 \text{ to } +75 \text{ }^{\circ}\text{C})$ 

Item		Symbol	min.	typ.*	max.	Unit	Condition	
	Α	$V_T^+$		1.0	2.0	V	V <sub>CC</sub> = 4.75 V	
Threshold	A	$V_T^-$	0.8	1.0		٧	V <sub>CC</sub> = 4.75 V	
voltage	В	$V_T^+$		1.0	2.0	٧	V <sub>CC</sub> = 4.75 V	
	Ь	$V_T^-$	0.8	0.9		٧	V <sub>CC</sub> = 4.75 V	
		$V_{OH}$	2.7			٧	$V_{CC} = 4.75 \text{ V}, I_{OH} = -400 \mu\text{A}$	
Output voltage		$V_{OL}$			0.4	V	$I_{OL} = 4 \text{ mA}$ $I_{OL} = 8 \text{ mA}$ $V_{CC} = 4.75 \text{ V}$	
		VOL	— — 0.5	٧	$I_{OL} = 8 \text{ mA}$			
		I <sub>IH</sub>			20	μΑ	$V_{CC} = 5.25 \text{ V}, V_{I} = 2.7 \text{ V}$	
Input current	Α	I <sub>IL</sub>			-0.4	mA	V <sub>CC</sub> = 5.25 V, V <sub>I</sub> = 0.4 V	
Input current	B, Clear	IIL			-0.8	ША		
		-			0.1	mA	$V_{CC} = 5.25 \text{ V}, V_{I} = 7 \text{ V}$	
Short-circuit ou current	ıtput	I <sub>OS</sub>	-20	-	-100	mA	V <sub>CC</sub> = 5.25 V	
Supply ourrent		1		4.7	11	mA	Ouiescent V <sub>CC</sub> = 5.25 V	
Supply current		Icc		19	27	IIIA	Triggered VCC = 5.25 V	
Input clamp vo	Itage	$V_{IK}$	_	_	-1.5	V	$V_{CC} = 4.75 \text{ V}, I_{IN} = -18 \text{ mA}$	

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Note: \* V<sub>CC</sub> = 5 V, Ta = 25°C

### **Switching Characteristics**

 $(V_{CC} = 5 \text{ V}, \text{Ta} = 25^{\circ}\text{C})$ 

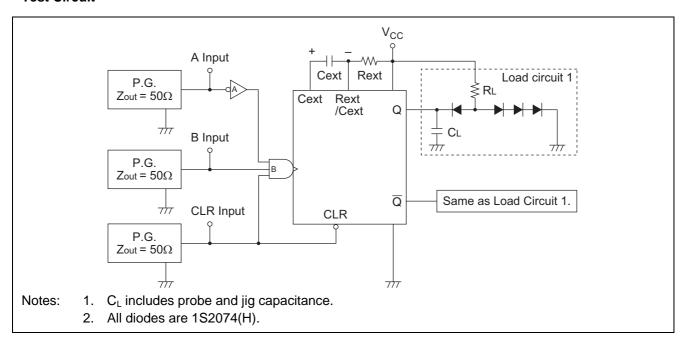
Item	Symbol	Inputs	Outputs	min.	typ.	max.	Unit	Condi	tion
	4	Α	Q	_	45	70	20		
	t <sub>PLH</sub>	В	Q	_	35	55	ns		
Propagation	4	Α	Q	_	50	80	no	$C_{\text{ext}} = 80 \text{ pF},$	
delay time	t <sub>PHL</sub>	В	Q	_	40	65	ns	$R_{ext} = 2 k\Omega$	
	t <sub>PHL</sub>	Clear	Q	_	35	55	ns		$C_L = 15 \text{ pF},$ $R_L = 2 \text{ k}\Omega$
	t <sub>PLH</sub>	Clear	Q	_	44	65	ns		
	t <sub>w (out)</sub> A or E	t <sub>w (out)</sub> A or B Q or Q		70	120	150		$C_{\text{ext}} = 80 \text{ pF},$ $R_{\text{ext}} = 2 \text{ k}\Omega$	
Output pulse width			20	47	70	$\begin{array}{c} \text{ns} & \begin{array}{c} C_{\text{ext}} = 0 \text{ pF,} \\ R_{\text{ext}} = 2 \text{ k}\Omega \end{array} \\ \hline C_{\text{ext}} = 100 \text{ pF,} \\ R_{\text{ext}} = 10 \text{ k}\Omega \end{array}$			
			600	670	750				
			6	6.7	7.5	ms	$C_{\text{ext}} = 1 \mu\text{F},$ $R_{\text{ext}} = 10 k\Omega$		

### Caution in use

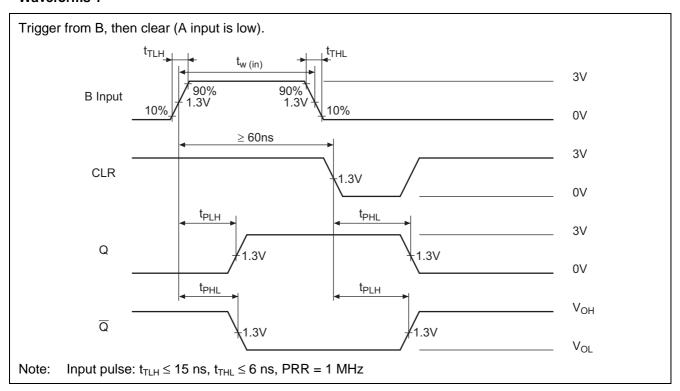
In order to prevent any malfunctions due to noise, connect a high frequency performance capacitor between Vcc and GND, and keep the wiring between the External components and Cext, Rext/Cext pins as short as possible.

### **Testing Method**

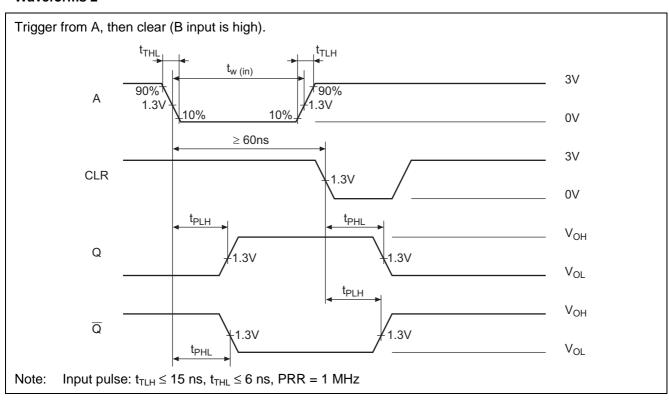
#### **Test Circuit**



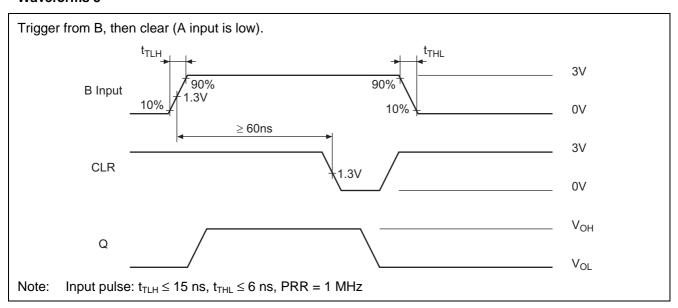
### Waveforms 1



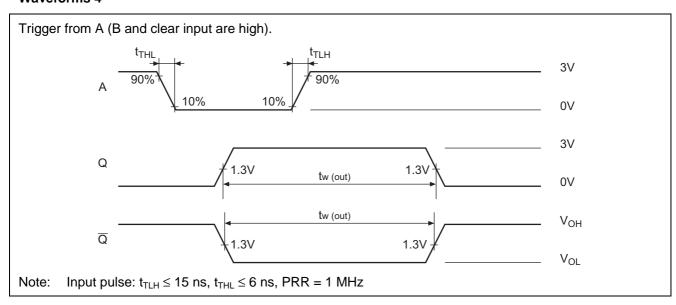
#### Waveforms 2



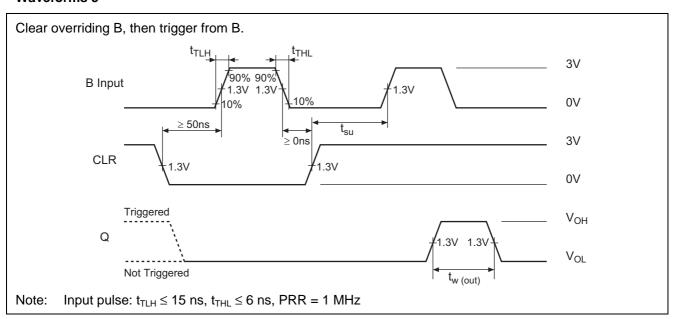
### Waveforms 3



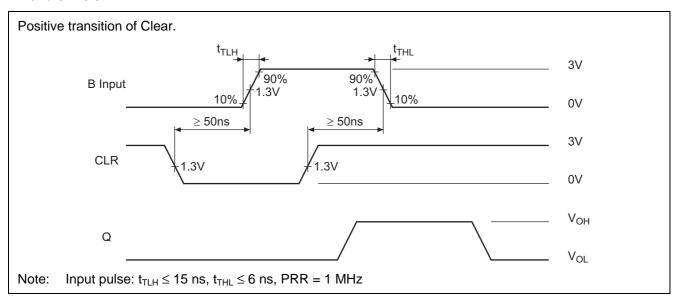
#### Waveforms 4



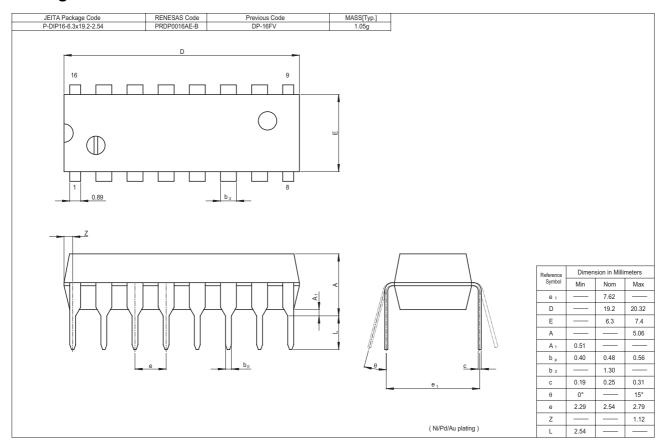
#### Waveforms 5

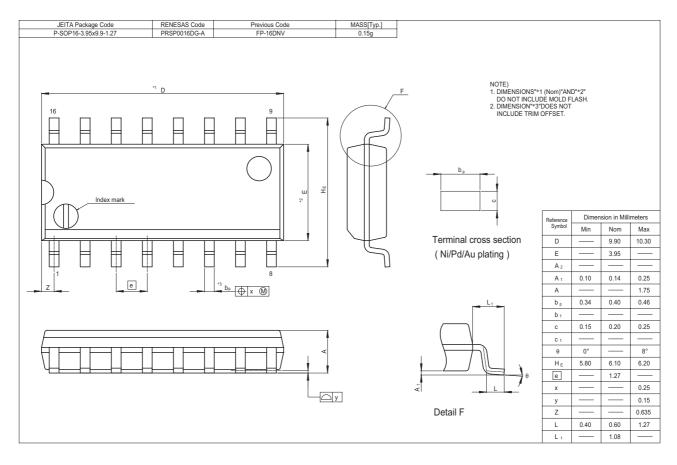


#### Waveforms 6



### **Package Dimensions**





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